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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Obsolete
Core Processor	ARM7®
Core Size	16/32-Bit
Speed	55MHz
Connectivity	I ² C, SPI, SSC, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, POR, PWM, WDT
Number of I/O	32
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.65V ~ 1.95V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-VFQFN Exposed Pad
Supplier Device Package	64-QFN (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/atmel/at91sam7s321-mu

2. Block Diagram

Figure 2-1. SAM7S512/256/128/64/321/161 Block Diagram

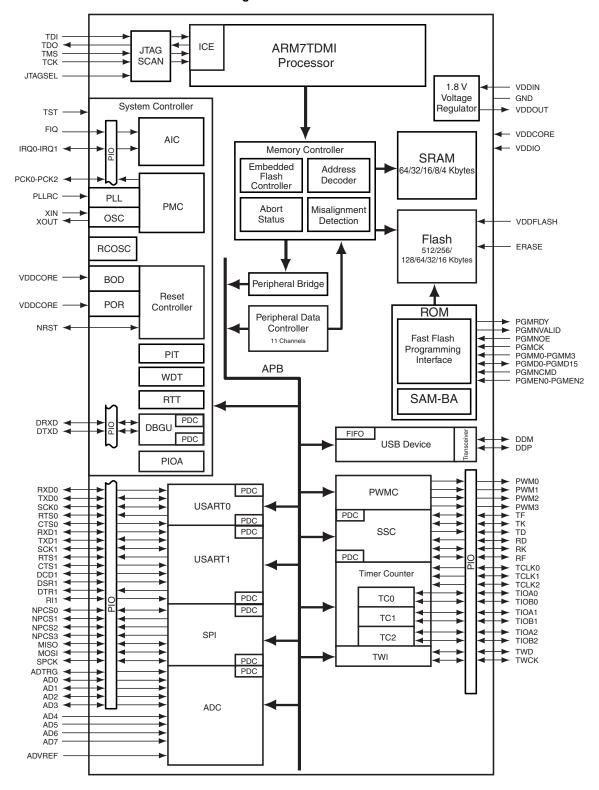
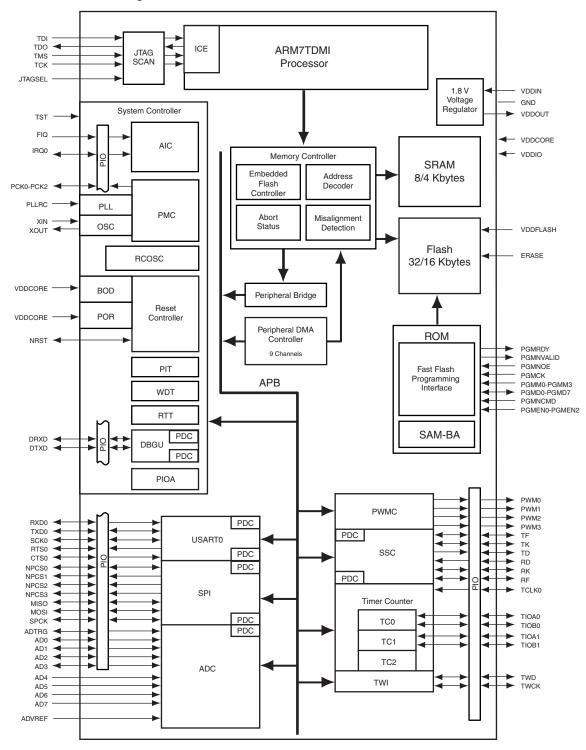




Figure 2-2. SAM7S32/16 Block Diagram





3. Signal Description

Table 3-1. Signal Description List

able 3-1. Signa	al Description List			
	Voltage and ADC Regulator Power Supply			
VDDIN	Input	Power		3.0 to 3.6V
VDDOUT	Voltage Regulator Output	Power		1.85V nominal
VDDFLASH	Flash Power Supply	Power		3.0V to 3.6V
VDDIO	I/O Lines Power Supply	Power		3.0V to 3.6V or 1.65V to 1.95V
VDDCORE	Core Power Supply	Power		1.65V to 1.95V
VDDPLL	PLL	Power		1.65V to 1.95V
GND	Ground	Ground		
XIN	Main Oscillator Input	Input		
XOUT	Main Oscillator Output	Output		
PLLRC	PLL Filter	Input		
PCK0 - PCK2	Programmable Clock Output	Output		
	·			
TCK	Test Clock	Input		No pull-up resistor
TDI	Test Data In	Input		No pull-up resistor
TDO	Test Data Out	Output		
TMS	Test Mode Select	Input		No pull-up resistor
JTAGSEL	JTAG Selection	Input		Pull-down resistor ⁽¹⁾
ERASE	Flash and NVM Configuration Bits Erase Command	Input	High	Pull-down resistor ⁽¹⁾
NRST	Microcontroller Reset	I/O	Low	Open-drain with pull-Up resistor
TST	Test Mode Select	Input	High	Pull-down resistor ⁽¹⁾
101	rest wode select	прис	riigii	T uni-down resistor
DRXD	Debug Receive Data	Input		
DTXD	Debug Transmit Data	Output		
IRQ0 - IRQ1	External Interrupt Inputs	Input		IRQ1 not present on SAM7S32/16
FIQ	Fast Interrupt Input	-		ING FIRST DIESERLOH SAMITSSZ/10
rių —	rast interrupt input	Input		
DAG - DAG4	Destrute on the first			Pulled-up input at reset
PA0 - PA31	Parallel IO Controller A	I/O		PA0 - PA20 only on SAM7S32/16



Table 3-1. Signal Description List (Continued)

Table 3-1. Signal Description List (Continued)				
		"	l .	
TWD	Two-wire Serial Data	I/O		
TWCK	Two-wire Serial Clock	I/O		
AD0-AD3	Analog Inputs	Analog		Digital pulled-up inputs at reset
AD4-AD7	Analog Inputs	Analog		Analog Inputs
ADTRG	ADC Trigger	Input		
ADVREF	ADC Reference	Analog		
PGMEN0-PGMEN2	Programming Enabling	Input		
PGMM0-PGMM3	Programming Mode	Input		
PGMD0-PGMD15	Programming Data	I/O		PGMD0-PGMD7 only on SAM7S32/16
PGMRDY	Programming Ready	Output	High	
PGMNVALID	Data Direction	Output	Low	
PGMNOE	Programming Read	Input	Low	
PGMCK	Programming Clock	Input		
PGMNCMD	Programming Command	Input	Low	

Note: 1. Refer to Section 6. "I/O Lines Considerations" on page 14.



4. Package and Pinout

The SAM7S512/256/128/64/321 are available in a 64-lead LQFP or 64-pad QFN package.

The SAM7S161 is available in a 64-Lead LQFP package.

The SAM7S32/16 are available in a 48-lead LQFP or 48-pad QFN package.

4.1 64-lead LQFP and 64-pad QFN Package Outlines

Figure 4-1 and Figure 4-2 show the orientation of the 64-lead LQFP and the 64-pad QFN package. A detailed mechanical description is given in the section Mechanical Characteristics of the full datasheet.

Figure 4-1. 64-lead LQFP Package (Top View)

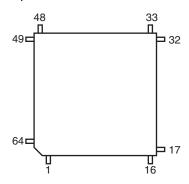
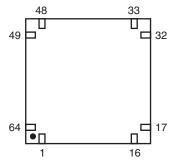


Figure 4-2. 64-pad QFN Package (Top View)





4.2 64-lead LQFP and 64-pad QFN Pinout

Table 4-1. SAM7S512/256/128/64/321/161 Pinout⁽¹⁾

1	ADVREF		
2	GND		
3	AD4		
4	AD5		
5	AD6		
6	AD7		
7	VDDIN		
8	VDDOUT		
9	PA17/PGMD5/AD0		
10	PA18/PGMD6/AD1		
11	PA21/PGMD9		
12	VDDCORE		
13	PA19/PGMD7/AD2		
14	PA22/PGMD10		
15	PA23/PGMD11		
16	PA20/PGMD8/AD3		

17	GND		
18	VDDIO		
19	PA16/PGMD4		
20	PA15/PGMD3		
21	PA14/PGMD2		
22	PA13/PGMD1		
23	PA24/PGMD12		
24	VDDCORE		
25	PA25/PGMD13		
26	PA26/PGMD14		
27	PA12/PGMD0		
28	PA11/PGMM3		
29	PA10/PGMM2		
30	PA9/PGMM1		
31	PA8/PGMM0		
32	PA7/PGMNVALID		
~ OEN .			

33	TDI	
34	PA6/PGMNOE	
35	PA5/PGMRDY	
36	PA4/PGMNCMD	
37	PA27/PGMD15	
38	PA28	
39	NRST	
40	TST	
41	PA29	
42	PA30	
43	PA3	
44	PA2/PGMEN2	
45	VDDIO	
46	GND	
47	PA1/PGMEN1	
48	PA0/PGMEN0	

49	TDO
50	JTAGSEL
51	TMS
52	PA31
53	TCK
54	VDDCORE
55	ERASE
56	DDM
57	DDP
58	VDDIO
59	VDDFLASH
60	GND
61	XOUT
62	XIN/PGMCK
63	PLLRC
64	VDDPLL

Note: 1. The bottom pad of the QFN package must be connected to ground.



4.3 48-lead LQFP and 48-pad QFN Package Outlines

Figure 4-3 and Figure 4-4 show the orientation of the 48-lead LQFP and the 48-pad QFN package. A detailed mechanical description is given in the section Mechanical Characteristics of the full datasheet.

Figure 4-3. 48-lead LQFP Package (Top View)

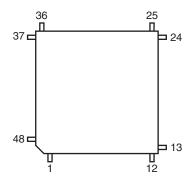
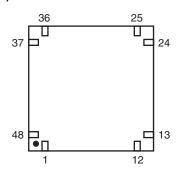


Figure 4-4. 48-pad QFN Package (Top View)



4.4 48-lead LQFP and 48-pad QFN Pinout

Table 4-2. SAM7S32/16 Pinout⁽¹⁾

1	ADVREF		
2	GND		
3	AD4		
4	AD5		
5	AD6		
6	AD7		
7	VDDIN		
8	VDDOUT		
9	PA17/PGMD5/AD0		
10	PA18/PGMD6/AD1		
11	PA19/PGMD7/AD2		
12	PA20/AD3		

13	VDDIO			
14	PA16/PGMD4			
15	PA15/PGMD3			
16	PA14/PGMD2			
17	PA13/PGMD1			
18	VDDCORE			
19	PA12/PGMD0			
20	PA11/PGMM3			
21	PA10/PGMM2			
22	PA9/PGMM1			
23	PA8/PGMM0			
24	PA7/PGMNVALID			

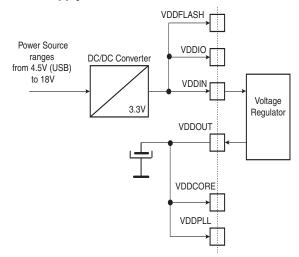
TDI		
PA6/PGMNOE		
PA5/PGMRDY		
PA4/PGMNCMD		
NRST		
TST		
PA3		
PA2/PGMEN2		
VDDIO		
GND		
PA1/PGMEN1		
PA0/PGMEN0		

37	TDO		
38	JTAGSEL		
39	TMS		
40	TCK		
41	VDDCORE		
42	ERASE		
43	VDDFLASH		
44	GND		
45	XOUT		
46	XIN/PGMCK		
47	PLLRC		
48	VDDPLL		

Note: 1. The bottom pad of the QFN package must be connected to ground.



Figure 5-1. 3.3V System Single Power Supply Schematic





7. Processor and Architecture

7.1 ARM7TDMI Processor

- RISC processor based on ARMv4T Von Neumann architecture
 - Runs at up to 55 MHz, providing 0.9 MIPS/MHz
- Two instruction sets
 - ARM® high-performance 32-bit instruction set
 - Thumb[®] high code density 16-bit instruction set
- Three-stage pipeline architecture
 - Instruction Fetch (F)
 - Instruction Decode (D)
 - Execute (E)

7.2 Debug and Test Features

- Integrated EmbeddedICE[™] (embedded in-circuit emulator)
 - Two watchpoint units
 - Test access port accessible through a JTAG protocol
 - Debug communication channel
- Debug Unit
 - Two-pin UART
 - Debug communication channel interrupt handling
 - Chip ID Register
- IEEE1149.1 JTAG Boundary-scan on all digital pins

7.3 Memory Controller

- Bus Arbiter
 - Handles requests from the ARM7TDMI and the Peripheral DMA Controller
- Address decoder provides selection signals for
 - Three internal 1 Mbyte memory areas
 - One 256 Mbyte embedded peripheral area
- Abort Status Registers
 - Source, Type and all parameters of the access leading to an abort are saved
 - Facilitates debug by detection of bad pointers
- Misalignment Detector
 - Alignment checking of all data accesses
 - Abort generation in case of misalignment
- Remap Command
 - Remaps the SRAM in place of the embedded non-volatile memory
 - Allows handling of dynamic exception vectors
- Embedded Flash Controller
 - Embedded Flash interface, up to three programmable wait states
 - Prefetch buffer, buffering and anticipating the 16-bit requests, reducing the required wait states
 - Key-protected program, erase and lock/unlock sequencer
 - Single command for erasing, programming and locking operations
 - Interrupt generation in case of forbidden operation



8. Memories

8.1 SAM7S512

- 512 Kbytes of Flash Memory, dual plane
 - 2 contiguous banks of 1024 pages of 256 bytes
 - Fast access time, 30 MHz single-cycle access in Worst Case conditions
 - · Page programming time: 6 ms, including page auto-erase
 - Page programming without auto-erase: 3 ms
 - Full chip erase time: 15 ms
 - 10,000 write cycles, 10-year data retention capability
 - 32 lock bits, protecting 32 sectors of 64 pages
 - Protection Mode to secure contents of the Flash
- 64 Kbytes of Fast SRAM
 - Single-cycle access at full speed

8.2 SAM7S256

- 256 Kbytes of Flash Memory, single plane
 - 1024 pages of 256 bytes
 - Fast access time, 30 MHz single-cycle access in Worst Case conditions
 - Page programming time: 6 ms, including page auto-erase
 - Page programming without auto-erase: 3 ms
 - Full chip erase time: 15 ms
 - 10,000 write cycles, 10-year data retention capability
 - 16 lock bits, protecting 16 sectors of 64 pages
 - Protection Mode to secure contents of the Flash
- 64 Kbytes of Fast SRAM
 - Single-cycle access at full speed

8.3 SAM7S128

- 128 Kbytes of Flash Memory, single plane
 - 512 pages of 256 bytes
 - Fast access time, 30 MHz single-cycle access in Worst Case conditions
 - Page programming time: 6 ms, including page auto-erase
 - Page programming without auto-erase: 3 ms
 - Full chip erase time: 15 ms
 - 10,000 write cycles, 10-year data retention capability
 - 8 lock bits, protecting 8 sectors of 64 pages
 - Protection Mode to secure contents of the Flash
- 32 Kbytes of Fast SRAM
 - Single-cycle access at full speed

8.4 SAM7S64

- 64 Kbytes of Flash Memory, single plane
 - 512 pages of 128 bytes



8.7 Memory Mapping

8.7.1 Internal SRAM

- The SAM7S512 embeds a high-speed 64-Kbyte SRAM bank.
- The SAM7S256 embeds a high-speed 64-Kbyte SRAM bank.
- The SAM7S128 embeds a high-speed 32-Kbyte SRAM bank.
- The SAM7S64 embeds a high-speed 16-Kbyte SRAM bank.
- The SAM7S321 embeds a high-speed 8-Kbyte SRAM bank.
- The SAM7S32 embeds a high-speed 8-Kbyte SRAM bank.
- The SAM7S161 embeds a high-speed 4-Kbyte SRAM bank.
- The SAM7S16 embeds a high-speed 4-Kbyte SRAM bank

After reset and until the Remap Command is performed, the SRAM is only accessible at address 0x0020 0000. After Remap, the SRAM also becomes available at address 0x0.

8.7.2 Internal ROM

The SAM7S Series embeds an Internal ROM. The ROM contains the FFPI and the SAM-BA program.

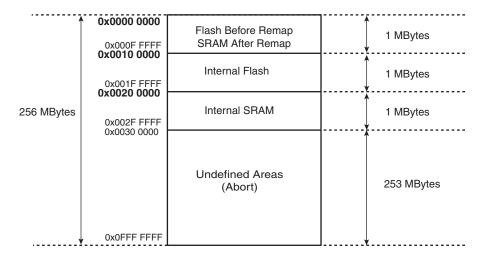
The internal ROM is not mapped by default.

8.7.3 Internal Flash

- The SAM7S512 features two contiguous banks (dual plane) of 256 Kbytes of Flash.
- The SAM7S256 features one bank (single plane) of 256 Kbytes of Flash.
- The SAM7S128 features one bank (single plane) of 128 Kbytes of Flash.
- The SAM7S64 features one bank (single plane) of 64 Kbytes of Flash.
- The SAM7S321/32 features one bank (single plane) of 32 Kbytes of Flash.
- The SAM7S161/16 features one bank (single plane) of 16 Kbytes of Flash.

At any time, the Flash is mapped to address 0x0010 0000. It is also accessible at address 0x0 after the reset and before the Remap Command.

Figure 8-2. Internal Memory Mapping





8.8 Embedded Flash

8.8.1 Flash Overview

- The Flash of the SAM7S512 is organized in two banks (dual plane) of 1024 pages of 256 bytes. The 524,288 bytes are organized in 32-bit words.
- The Flash of the SAM7S256 is organized in 1024 pages (single plane) of 256 bytes. The 262,144 bytes are organized in 32-bit words.
- The Flash of the SAM7S128 is organized in 512 pages (single plane) of 256 bytes. The 131,072 bytes are organized in 32-bit words.
- The Flash of the SAM7S64 is organized in 512 pages (single plane) of 128 bytes. The 65,536 bytes are organized in 32-bit words.
- The Flash of the SAM7S321/32 is organized in 256 pages (single plane) of 128 bytes. The 32,768 bytes are organized in 32-bit words.
- The Flash of the SAM7S161/16 is organized in 256 pages (single plane) of 64 bytes. The 16,384 bytes are organized in 32-bit words.
- The Flash of the SAM7S512/256/128 contains a 256-byte write buffer, accessible through a 32-bit interface.
- The Flash of the SAM7S64/321/32/161/16 contains a 128-byte write buffer, accessible through a 32-bit interface.

The Flash benefits from the integration of a power reset cell and from the brownout detector. This prevents code corruption during power supply changes, even in the worst conditions.

When Flash is not used (read or write access), it is automatically placed into standby mode.

8.8.2 Embedded Flash Controller

The Embedded Flash Controller (EFC) manages accesses performed by the masters of the system. It enables reading the Flash and writing the write buffer. It also contains a User Interface, mapped within the Memory Controller on the APB. The User Interface allows:

- programming of the access parameters of the Flash (number of wait states, timings, etc.)
- starting commands such as full erase, page erase, page program, NVM bit set, NVM bit clear, etc.
- getting the end status of the last command
- getting error status
- programming interrupts on the end of the last commands or on errors

The Embedded Flash Controller also provides a dual 32-bit prefetch buffer that optimizes 16-bit access to the Flash. This is particularly efficient when the processor is running in Thumb mode.

Two EFCs are embedded in the SAM7S512 to control each bank of 256 Kbytes. Dual plane organization allows concurrent Read and Program. Read from one memory plane may be performed even while program or erase functions are being executed in the other memory plane.

One EFC is embedded in the SAM7S256/128/64/32/321/161/16 to control the single plane 256/128/64/32/16 Kbytes.



The 8 NVM bits are software programmable through the EFC User Interface. The command "Set Lock Bit" enables the protection. The command "Clear Lock Bit" unlocks the lock region.

Asserting the ERASE pin clears the lock bits, thus unlocking the entire Flash.

8.8.3.6 SAM7S161/16

The Embedded Flash Controller manages 8 lock bits to protect 8 regions of the flash against inadvertent flash erasing or programming commands. The SAM7S161/16 contains 8 lock regions and each lock region contains 32 pages of 64 bytes. Each lock region has a size of 2 Kbytes.

If a locked-region's erase or program command occurs, the command is aborted and the LOCKE bit in the MC_FSR register rises and the interrupt line rises if the LOCKE bit has been written at 1 in the MC_FMR register.

The 8 NVM bits are software programmable through the EFC User Interface. The command "Set Lock Bit" enables the protection. The command "Clear Lock Bit" unlocks the lock region.

Asserting the ERASE pin clears the lock bits, thus unlocking the entire Flash.

Table 8-1 summarizes the configuration of the eight devices.

Table 8-1. Flash Configuration Summary

SAM7S512	32	64	256 bytes
SAM7S256	16	64	256 bytes
SAM7S128	8	64	256 bytes
SAM7S64	16	32	128 bytes
SAM7S321/32	8	32	128 bytes
SAM7S161/16	8	32	64 bytes

8.8.4 Security Bit Feature

The SAM7S Series features a security bit, based on a specific NVM Bit. When the security is enabled, any access to the Flash, either through the ICE interface or through the Fast Flash Programming Interface, is forbidden. This ensures the confidentiality of the code programmed in the Flash.

This security bit can only be enabled, through the Command "Set Security Bit" of the EFC User Interface. Disabling the security bit can only be achieved by asserting the ERASE pin at 1, and after a full flash erase is performed. When the security bit is deactivated, all accesses to the flash are permitted.

It is important to note that the assertion of the ERASE pin should always be longer than 50 ms.

As the ERASE pin integrates a permanent pull-down, it can be left unconnected during normal operation. However, it is safer to connect it directly to GND for the final application.

8.8.5 Non-volatile Brownout Detector Control

Two general purpose NVM (GPNVM) bits are used for controlling the brownout detector (BOD), so that even after a power loss, the brownout detector operations remain in their state.

These two GPNVM bits can be cleared or set respectively through the commands "Clear General-purpose NVM Bit" and "Set General-purpose NVM Bit" of the EFC User Interface.

- GPNVM Bit 0 is used as a brownout detector enable bit. Setting the GPNVM Bit 0 enables the BOD, clearing it
 disables the BOD. Asserting ERASE clears the GPNVM Bit 0 and thus disables the brownout detector by default.
- The GPNVM Bit 1 is used as a brownout reset enable signal for the reset controller. Setting the GPNVM Bit 1 enables the brownout reset when a brownout is detected, Clearing the GPNVM Bit 1 disables the brownout reset. Asserting ERASE disables the brownout reset by default.



dbgu_irq power_on_reset pmc_irq rstc_irq force ntrst MCK periph_nreset dbgu_irq Debug → force_ntrst Unit dbgu_rxd ▶ dbgu_txd security_bit MCK debug Periodic Interval → pit_irq periph_nreset Timer flash_poe SLCK Real-Time → rtt_irq Timer flash_wrdis periph_nreset cal SLCK debug idle Watchdog gpnvm[0..1] → wdt_irq Timer proc_nreset wdt_fault WDRPROC gpnvm[1]gpnvm[0] MCK bod_rst_en → flash_wrdis BOD proc_nreset power_on_reset periph_nreset Reset → jtag_nreset → proc_nreset Voltage Controller POR ➤ flash_poe Regulator standby Mode Controller rstc_irq NRST cal · SLCK SLCK RCOSC → periph_clk[2..14] **UDPCK** → pck[0-2] periph_clk[11] Power XIN MAINCK OSC Management → PCK periph_nreset XOUT Controller → UDPCK periph_irq[11] → MCK usb_suspend PLLRC PLL PLLCK → pmc_irq → idle periph_nreset periph_clk[4..14] usb_suspend periph_nreset periph_irq{2] periph_nreset periph_clk[2] → irq0-irq1 periph_irq[4..14] dbgu_rxd PIO → fiq Controller → dbgu_txd in PA0-PA31 out enable

Figure 9-1. System Controller Block Diagram (SAM7S512/256/128/64/321/161)



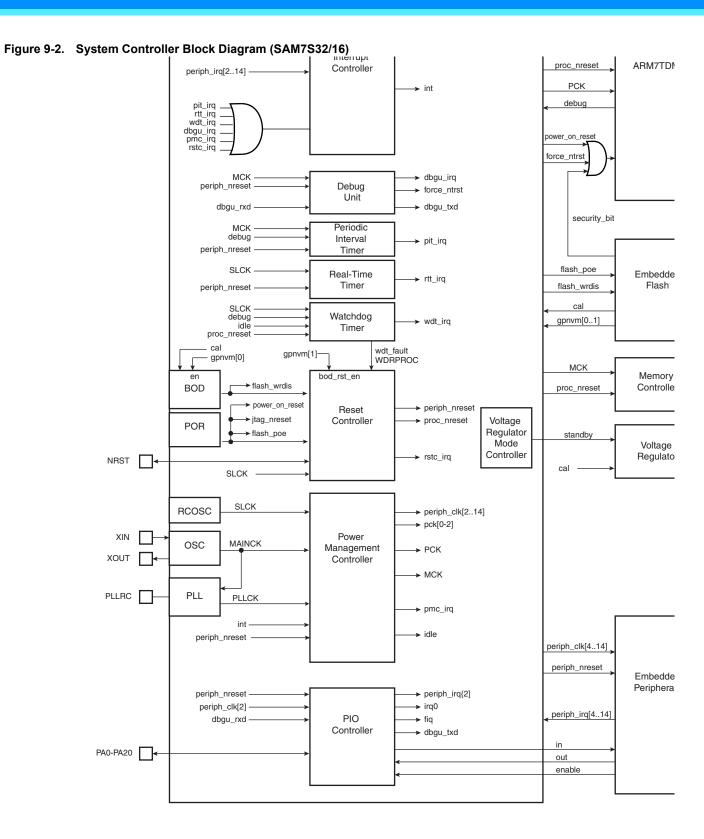




Table 10-2. Peripheral Identifiers (SAM7S32/16)

	· · · · · · · · · · · · · · · · · · ·		
0	AIC	Advanced Interrupt Controller	FIQ
1	SYSC ⁽¹⁾	System	
2	PIOA	Parallel I/O Controller A	
3	Reserved		
4	ADC ⁽¹⁾	Analog-to Digital Converter	
5	SPI	Serial Peripheral Interface	
6	US	USART	
7	Reserved		
8	SSC	Synchronous Serial Controller	
9	TWI	Two-wire Interface	
10	PWMC	PWM Controller	
11	Reserved		
12	TC0	Timer/Counter 0	
13	TC1	Timer/Counter 1	
14	TC2	Timer/Counter 2	
15 - 29	Reserved		
30	AIC	Advanced Interrupt Controller	IRQ0
31	Reserved		

10.3 Peripheral Multiplexing on PIO Lines

The SAM7S Series features one PIO controller, PIOA, that multiplexes the I/O lines of the peripheral set.

PIO Controller A controls 32 lines (21 lines for SAM7S32/16). Each line can be assigned to one of two peripheral functions, A or B. Some of them can also be multiplexed with the analog inputs of the ADC Controller.

Table 10-3, "Multiplexing on PIO Controller A (SAM7S512/256/128/64/321/161)," on page 35 and Table 10-4, "Multiplexing on PIO Controller A (SAM7S32/16)," on page 36 define how the I/O lines of the peripherals A, B or the analog inputs are multiplexed on the PIO Controller A. The two columns "Function" and "Comments" have been inserted for the user's own comments; they may be used to track how pins are defined in an application.

Note that some peripheral functions that are output only may be duplicated in the table.

All pins reset in their Parallel I/O lines function are configured as input with the programmable pull-up enabled, so that the device is maintained in a static state as soon as a reset is detected.



10.4 PIO Controller A Multiplexing

Table 10-3. Multiplexing on PIO Controller A (SAM7S512/256/128/64/321/161)

PA0	PWM0	TIOA0	High-Drive	
PA1	PWM1	TIOB0	High-Drive	
PA2	PWM2	SCK0	High-Drive	
PA3	TWD	NPCS3	High-Drive	
PA4	TWCK	TCLK0		
PA5	RXD0	NPCS3		
PA6	TXD0	PCK0		
PA7	RTS0	PWM3		
PA8	CTS0	ADTRG		
PA9	DRXD	NPCS1		
PA10	DTXD	NPCS2		
PA11	NPCS0	PWM0		
PA12	MISO	PWM1		
PA13	MOSI	PWM2		
PA14	SPCK	PWM3		
PA15	TF	TIOA1		
PA16	TK	TIOB1		
PA17	TD	PCK1	AD0	
PA18	RD	PCK2	AD1	
PA19	RK	FIQ	AD2	
PA20	RF	IRQ0	AD3	
PA21	RXD1	PCK1		
PA22	TXD1	NPCS3		
PA23	SCK1	PWM0		
PA24	RTS1	PWM1		
PA25	CTS1	PWM2		
PA26	DCD1	TIOA2		
PA27	DTR1	TIOB2		
PA28	DSR1	TCLK1		
PA29	RI1	TCLK2		
PA30	IRQ1	NPCS2		
PA31	NPCS1	PCK2		



Table 10-4. Multiplexing on PIO Controller A (SAM7S32/16)

Table 10-4.	wuttplexing on F	210 Controller A (SA	IVI 7 3 3 2 / 10)	
PA0	PWM0	TIOA0	High-Drive	
PA1	PWM1	TIOB0	High-Drive	
PA2	PWM2	SCK0	High-Drive	
PA3	TWD	NPCS3	High-Drive	
PA4	TWCK	TCLK0		
PA5	RXD0	NPCS3		
PA6	TXD0	PCK0		
PA7	RTS0	PWM3		
PA8	CTS0	ADTRG		
PA9	DRXD	NPCS1		
PA10	DTXD	NPCS2		
PA11	NPCS0	PWM0		
PA12	MISO	PWM1		
PA13	MOSI	PWM2		
PA14	SPCK	PWM3		
PA15	TF	TIOA1		
PA16	TK	TIOB1		
PA17	TD	PCK1	AD0	
PA18	RD	PCK2	AD1	
PA19	RK	FIQ	AD2	
PA20	RF	IRQ0	AD3	



Table 11-3. 48-pad QFN Package Dimensions (in mm)

	o paa qiiri ac		(,					
Symbol								
А	_	_	090	_	_	0.035		
A1	_	_	0.050	_	_	0.002		
A2	_	0.65	0.70	_	0.026	0.028		
A3	0.20 REF				0.008 REF			
b	0.18	0.20	0.23	0.007	0.008	0.009		
D	7.00 bsc				0.276 bsc			
D2	5.45	5.60	5.75	0.215	0.220	0.226		
E	7.00 bsc				0.276 bsc			
E2	5.45	5.60	5.75	0.215	0.220	0.226		
L	0.35	0.40	0.45	0.014	0.016	0.018		
е	0.50 bsc				0.020 bsc			
R	0.09	_	_	0.004	_	1		
Tolerances of Form and Position								
aaa	0.10				0.004			
bbb	0.10				0.004	0.226		
ccc	0.05			0.002				



12. SAM7S Ordering Information

 Table 12-1.
 SAM7S Series Ordering Information

MLR A Ordering Code	MLR B Ordering Code	MLR C Ordering Code	MLR D Ordering Code	Package	Package Type	Temperature Operating Range
AT91SAM7S16-AU AT91SAM7S16-MU	-	-	-	LQFP 48 QFN 48	Green	Industrial (-40· C to 85· C)
AT91SAM7S161-AU	_	-	-	LQFP 64	Green	Industrial (-40· C to 85· C)
AT91SAM7S32-AU-001 AT91SAM7S32-MU	AT91SAM7S32B-AU AT91SAM7S32B-MU			LQFP 48 QFN 48	Green	Industrial (-40· C to 85· C)
AT91SAM7S321-AU AT91SAM7S321-MU	_	-	-	LQFP 64 QFN 64	Green	Industrial (-40· C to 85· C)
-	AT91SAM7S64B-AU AT91SAM7S64B-MU	AT91SAM7S64C-AU AT91SAM7S64C-MU	-	LQFP 64 QFN 64	Green	Industrial (-40· C to 85· C)
-	AT91SAM7S128-AU-001 AT91SAM7S128-MU	AT91SAM7S128C-AU AT91SAM7S128C-MU	AT91SAM7S128D-AU AT91SAM7S128D-MU	LQFP 64 QFN 64	Green	Industrial (-40· C to 85· C)
-	AT91SAM7S256-AU-001 AT91SAM7S256-MU	AT91SAM7S256C-AU AT91SAM7S256C-MU	AT91SAM7S256D-AU AT91SAM7S256D-MU	LQFP 64 QFN 64	Green	Industrial (-40· C to 85· C)
AT91SAM7S512-AU AT91SAM7S512-MU	AT91SAM7S512B-AU AT91SAM7S512B-MU	-	-	LQFP 64 QFN 64	Green	Industrial (-40· C to 85· C)

